

A non-Hermitian Hamiltonian description of the dynamic Mott transition

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Dynamic Mott transitions: Motivation

General interest in understanding nonequilibrium transitions in quantum many-body systems:

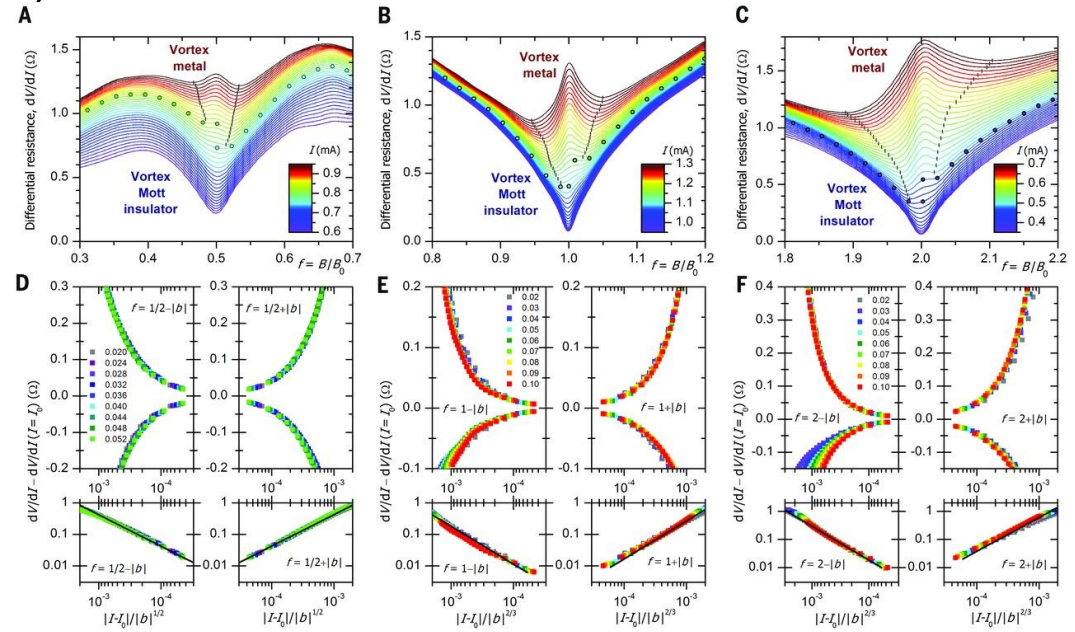
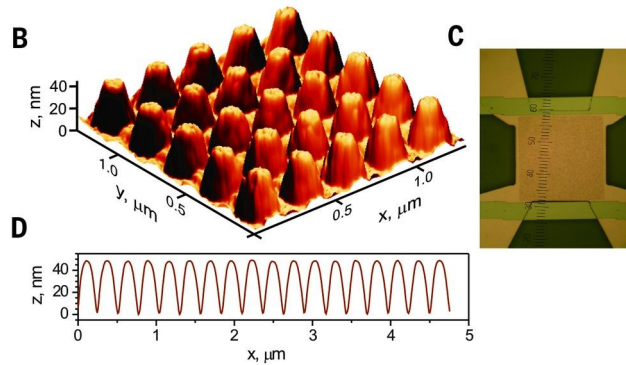
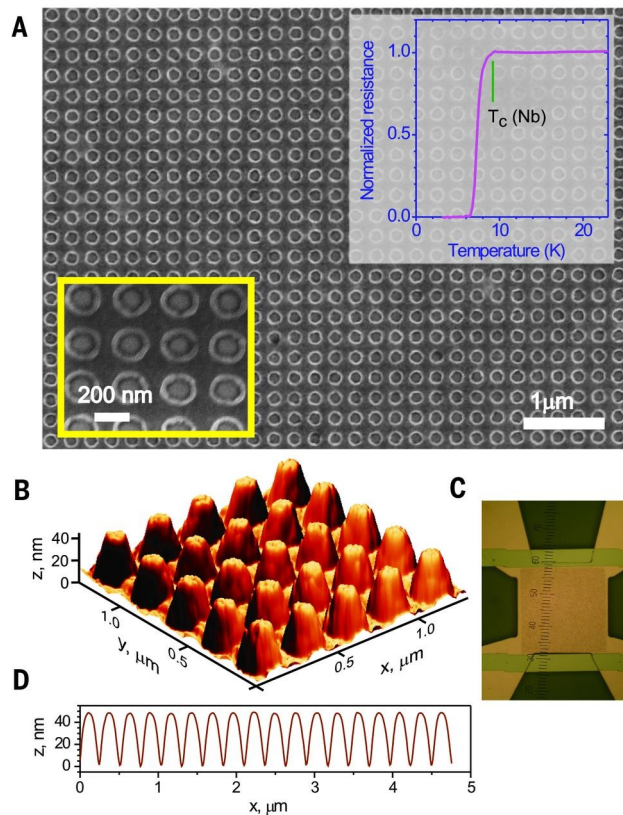
- (a) Is the transition continuous? What symmetries are broken? What are the critical exponents? Do they differ from corresponding equilibrium transitions?
- (b) How different are dynamic Mott transitions from noninteracting counterparts (e.g. dielectric breakdown in semiconductors)?
- (c) What is the role played by dissipative processes? Is a “Hamiltonian” formulation possible?
- (d) How does disorder affect the nonequilibrium transition?

Practical: Possibility of use in switching devices

C. H. Ahn, J-M. Triscone, and J. Mannhart, Nature (2003)

A current driven vortex Mott transition

N. Poccia et al., Science (2015)



$$\frac{dV}{dI} = F \left[\frac{|I - I_0|}{|f - f_c|^\epsilon} \right]$$

Critical current

Frustration factor (vortex filling)

$$f = 1, 2 \Rightarrow \epsilon \approx 2/3,$$

$$f = 1/2 \Rightarrow \epsilon \approx 1/2$$

Physical mechanism

As in semiconductors, electrical conduction in gapped phase proceeds through creation of free particle-hole excitations by Landau-Zener tunnelling.

T. Oka and H. Aoki, PRB (2010); M. Eckstein, T. Oka, and P. Werner, PRL (2010); A. G. Green and S. L. Sondhi, PRL (2005)

Landau-Zener tunneling known to get enhanced in semiconductors in the presence of dissipation.

E. Shimshoni and A. Stern, PRB (1993)

Q: What happens close to the Mott transition? What is the role of dissipation?

A: Dissipation enhances Landau-Zener tunneling in Mott insulators and ultimately leads to collapse of Mott gap. In the absence of dissipation, Mott gap not renormalized.

Method

Use Landau-Dykhne formula:
A. M. Dykhne, JETP (1962)

$$P_{01} = |\langle 1|0 \rangle|^2 = e^{-2\gamma},$$

$$\gamma = \frac{1}{\hbar} \Im \int_{-\infty}^{\infty} dt (E_1 - E_0)[\Psi(t)],$$

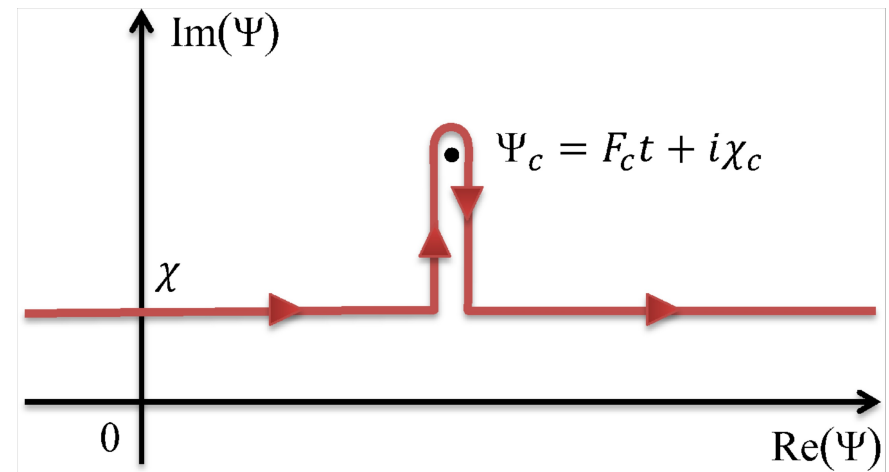
$$\Psi = Ft + i\chi$$

Time-dependent phase factor
related to driving field

Extension to complex plane

Finite imaginary part comes from
branch points in the complex
 Ψ -plane where the spectral gap
closes.

$$\gamma = \frac{1}{\hbar F} \Re \int_{\chi}^{\chi_c} d\chi' [E_1(\chi') - E_0(\chi')]$$



Completely determined by the imaginary part of Ψ !

Hubbard chain, no dissipation:
Oka & Aoki, PRB (2010)

$$\gamma \approx (E_1 - E_0)^2 / v F \equiv \Delta^2 / v F,$$

$$v = |(d\Delta/dt)/F|$$

Dissipation and non-Hermiticity

Is a “Hamiltonian” description possible for nonequilibrium steady states? **Yes!**

Consider Legendre transformed Hamiltonian $H' = H - i\lambda J$

T. Antal et al., Phys. Rev. Lett. 78 (1997);

J. Cardy and P. Suranyi, Nucl. Phys. B (2000)

Model invariant under simultaneous Parity (P) & Time Reversal (T).
PT-symmetry generically arises in situation of balanced gain and loss.
C. Bender and S. Boettcher, PRL (1998).

Real λ eqv. to imaginary vector potential.

For small λ , spectral gap in $H \Rightarrow \langle J \rangle = 0$ (Real eigenvalues for H')

For large λ , eigenstates those of $J \Rightarrow \langle J \rangle \neq 0$ (Complex eigenvalues)

Dissipation and non-Hermiticity

Intuitively construct a density matrix for the non-Hermitian model:

$$\rho(t) = \frac{e^{-iH't} \rho(0) e^{iH't}}{\text{tr}[e^{-iH't} \rho(0) e^{iH't}]}, \quad \langle A \rangle \equiv \text{tr}(\rho A)$$

Finite real part of λ necessary for relaxation to a nonequilibrium steady state:

$$\frac{d\langle J \rangle}{dt} = -\lambda(\langle J^2 \rangle - \langle J \rangle^2)$$

Model then does describe a nonequilibrium (dissipative) metal-insulator transition. λ characterizes both dissipation & drive.

Below some critical field F_c (corresponding to a critical λ_c) the spectral gap is finite and $\langle J \rangle = 0$, eigenvalues of H' are real. At larger fields, a finite current flows, eigenvalues are complex. Eigenstates break PT symmetry.

Nonequilibrium phase transition brought about by tuning λ mirrors the electric field driven dynamic Mott transition!

Fermionic dynamic Mott transition

Fermionic Hubbard chain at half filling subjected to vector potential $\Psi = F t + i \chi$:

$$H = -t \sum_{\langle ij \rangle, \sigma} [e^{i\Psi(t)} c_{i\sigma}^+ c_{j\sigma} + e^{-i\Psi(t)} c_{j\sigma}^+ c_{i\sigma}] + \sum_i n_{i\uparrow} n_{i\downarrow}$$

Imaginary component of vector potential arises in an effective description of hopping in the presence of energy relaxation processes (bath).

Physical meaning: Hopping amplitudes along and opposite the driving field have different magnitudes.

Examples:

- (1) Transport in disordered semiconductors in strong electric field (B. Shklovskii, Sol. St. Comm. (1981))
- (2) Mott transition in Vortex systems in tilted magnetic fields (Lehrer & Nelson, PRB (1998))

Fermionic dynamic Mott transition

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Solvable by Bethe ansatz even for complex Ψ !
Oka and Aoki, PRB (2010)

$$L k_j = 2\pi I_j + \Psi(t) - \sum_{\alpha=1}^{N_{\downarrow}} \theta(\sin(k_j) - \lambda_{\alpha}),$$
$$\sum_{j=1}^N \theta(\sin(k_j) - \lambda_{\alpha}) = 2\pi J_{\alpha} - \sum_{\beta=1}^{N_{\downarrow}} \theta\left(\frac{\lambda_{\alpha} - \lambda_{\beta}}{2}\right)$$
$$I_j = N_{\downarrow}/2 \pmod{1},$$
$$J_{\alpha} = (N - N_{\downarrow} + 1)/2 \pmod{1},$$
$$\theta(x) = -2 \arctan(x/u),$$
$$u = U/4t$$

Solutions are in general complex.

Fermionic dynamic Mott transition

Real part of Ψ linearly increases the crystal momenta with time, and is responsible for Bloch oscillations.

Landau-Zener tunneling takes place at some $k = \pm\pi + ib$ since the bandgap is smallest at the Brillouin zone boundaries.

$$\Delta(b) = 4t \left[u - \cosh(b) + \int_{-\infty}^{\infty} \frac{d\omega}{2\pi} \frac{J_1(\omega) e^{\omega \sinh(b)}}{1 + e^{2u|\omega|}} \right],$$

$$\Delta(b_c) \equiv 0,$$

$$b_c = \sinh^{-1}(u)$$

Lieb & Wu, PRL (1968),
Fukui & Kawakami, PRB (1998)

By increasing the imaginary part of the vector potential, the Mott gap gets ultimately closed & Landau-Zener factor collapses:

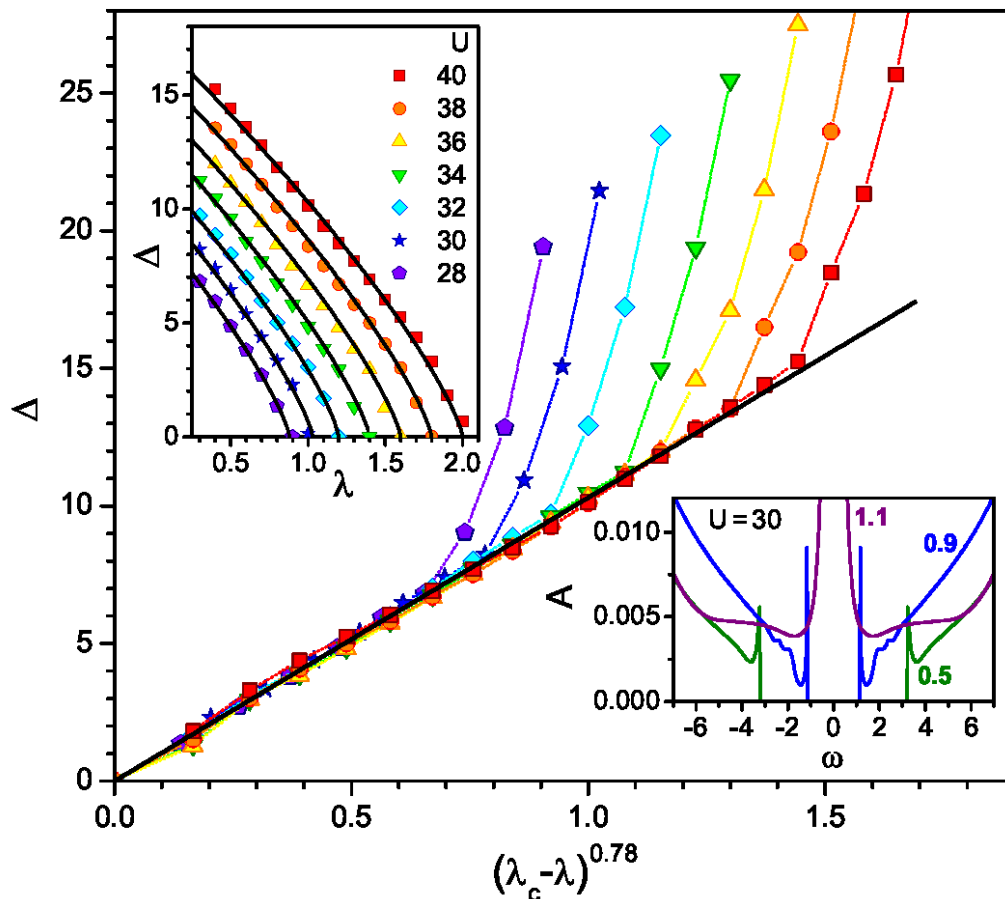
$$\Delta(\chi) \approx C_1 \sqrt{\chi_c - \chi}$$

$$\gamma = C (\chi_c - \chi)^{3/2}$$

Same dependence on electric field follows.

Fermions: $D > 1$

Bethe ansatz not possible in higher dimensions. We use DMFT with Iterative Perturbation Theory (IPT) based impurity solver:



See larger critical exponent for gap scaling in 2D and 3D.

$$\Delta(\lambda) \sim (\lambda_c - \lambda)^{0.78}, \quad D=2,$$

$$\Delta(\lambda) \sim (\lambda_c - \lambda)^{0.86}, \quad D=3$$

3D result lies close to exponent =1 predicted in mean-field treatments of equilibrium Hubbard models.

Florens and Georges, PRB (2004)
Zhang and Rice, PRB (1970)

Dynamic Mott transition for dissipative Bosons

Consider problem of Mott transition of field-induced vortices in superconducting 2D proximity arrays (square lattice).

External current acts like an electric field on vortex “charges”. For dissipative (overdamped case), we get PT-symmetric Schrödinger equation [also see J. Rubinstein et al. PRL (2007); N. M. Chtchelkachev, PRL (2012)]

$$\frac{\partial \psi}{\partial t} = -D \nabla^2 \psi + i(I/\rho) x \psi + m^2 \psi + 2u|\psi|^2 \psi$$

BCs: Vortices confined in normal regions of size L . In the surrounding superconducting phase, $\psi=0$. Confinement leads to spectral gap. Examine evolution of gap with current:

$$E_1 - E_0 \approx 2 E_T \sqrt{\eta \left(1 - I^2/I_c^2\right)},$$
$$E_T = D/L^2, \quad \eta = \left(\pi^2/\sqrt{2} (I_c L/E_T \rho)\right)$$



$$\gamma \sim (I_c - I)^{3/2}$$

Agrees with N. Poccia et al., Science (2015)

Summary and Outlook

- We studied dynamic Mott transition in a dissipative fermionic half-filled Hubbard model and a bosonic vortex system.
- Nonequilibrium steady states were identified as stationary states of certain non-Hermitian Hamiltonians endowed with PT-symmetry.
- Field-driven Mott transition in these systems is a PT-symmetry breaking transition. Key difference from non-dissipative case is renormalization of Landau-Zener factor which can be large even if the driving field is applied deep within the Mott phase.
- Critical exponent for Landau-Zener factor agrees with experiments on vortex Mott transition in superconducting proximity arrays.

- We need a microscopic derivation of fermionic non-Hermitian models beginning with a Hermitian system coupled to a bath.
- We would like to understand the dynamic Mott transition in the presence of disorder.